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HMC241QS16 / 241QS16E



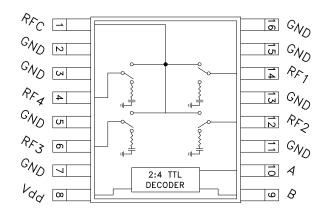
GaAs MMIC SP4T NON-REFLECTIVE SWITCH, DC - 3.5 GHz

Typical Applications

The HMC241QS16 & HMC241QS16E are ideal for:

- Base Stations & Portable Wireless
- CATV / DBS
- Wireless Local Loop
- Test Equipment

Functional Diagram



Features

RoHS Compliant Product

Low Insertion Loss (2 GHz): 0.5 dB

Single Positive Supply: Vdd = +5V

Integrated 2:4 TTL Decoder

16 Lead QSOP Package

General Description

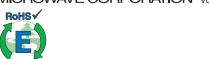
The HMC241QS16 & HMC241QS16E are general purpose low-cost non-reflective SP4T switches in 16-lead QSOP packages. Covering DC - 3.5 GHz, this switch offers high isolation and has a low insertion loss of 0.5 dB at 2 GHz. The switch offers a single positive bias and true TTL/CMOS compatibility. A 2:4 decoder is integrated on the switch requiring only 2 control lines and a positive bias to select each path, replacing 8 control lines normally required by GaAs SP4T switches.

Electrical Specifications, $T_{\Delta} = +25^{\circ}$ C, For TTL Control and Vdd = +5V in a 50 Ohm System

Parameter	Frequency	Min.	Тур.	Max.	Units
Insertion Loss	DC - 1.0 GHz DC - 2.0 GHz DC - 2.5 GHz DC - 3.5 GHz		0.5 0.5 0.6 1.0	0.8 0.8 0.9 1.5	dB dB dB dB
Isolation	DC - 1.0 GHz DC - 2.0 GHz DC - 2.5 GHz DC - 3.5 GHz	40 32 28 23	45 36 32 26		dB dB dB dB
Return Loss "On State"	DC - 2.5 GHz DC - 3.5 GHz	17 9	21 12		dB dB
Return Loss RF1-4 "Off State"	0.3 - 3.5 GHz 0.5 - 2.5 GHz	8 12	12 16		dB dB
Input Power for 1dB Compression	0.3 - 3.5 GHz	22	25		dBm
Input Third Order Intercept (Two-Tone Input Power = +7 dBm Each Tone)	0.3 - 3.5 GHz	40	44		dBm
Switching Characteristics	0.3 - 3.5 GHz				
tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)			40 150		ns ns

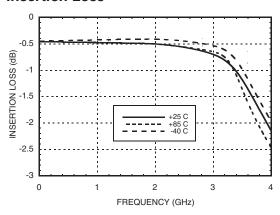


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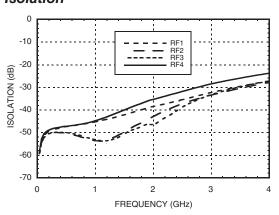


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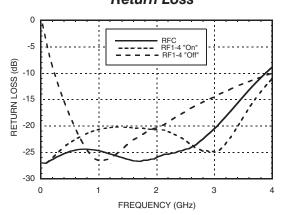
Insertion Loss



Isolation



Return Loss



Bias Voltage & Current

Vdd Range = +5.0 Vdc ± 10%			
Vdd Idd (Typ.) Idd (Max.) (Vdc) (mA) (mA)			
+5.0	4.0	7.0	

Truth Table

Control Input		Signal Path State	
Α	В	RFCOM to:	
LOW	LOW	RF1	
HIGH	LOW	RF2	
LOW	HIGH	RF3	
HIGH	HIGH	RF4	

TTL/CMOS Control Voltages

State	Bias Condition
Low	0 to +0.8 Vdc @ 5uA Typ.
High	+2.0 to +5.0 Vdc @ 70 uA Typ.

NOTE:

DC Blocking capacitors are required at ports RFC and RF1, 2, 3, 4.

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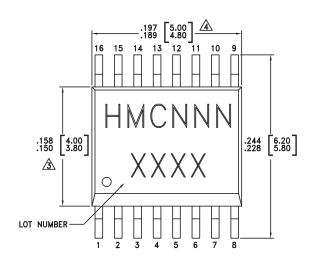


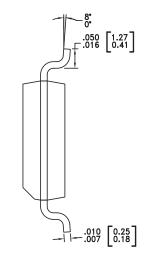
Absolute Maximum Ratings

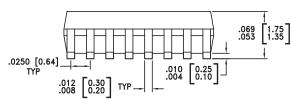
Bias Voltage Range (Port Vdd)	+7.0 Vdc
Control Voltage Range (A & B)	-0.5V to Vdd +1 Vdc
Channel Temperature	150 °C
Thermal Resistance (Insertion Loss Path)	210 °C/W
Thermal Resistance (Terminated Path)	250 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
Maximum Input Power Vdd = +5 Vdc	+20 dBm (0.05 - 0.5 GHz) +27 dBm (0.5 - 3.5 GHz)



Outline Drawing







NOTES:

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
 ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.

Package Information

Part Number	Package Body Material	Leadframe Plating	MSL Rating	Package Marking [3]
HMC241QS16	Low Stress Injection Molded Plastic Silica and Silicon Impregnated	Sn/Pb Solder	MSL1 [1]	HMC241 XXXX
HMC241QS16E	RoHS-compliant Low Stress Injection Molded Plastic Silica and Silicon Impregnated	100% Matte Tin	MSL1 [2]	HMC241 XXXX

- [1] Max peak reflow temperature of 235 $^{\circ}\text{C}$
- [2] Max peak reflow temperature of 260 °C
- [3] 4-Digit lot number XXXX

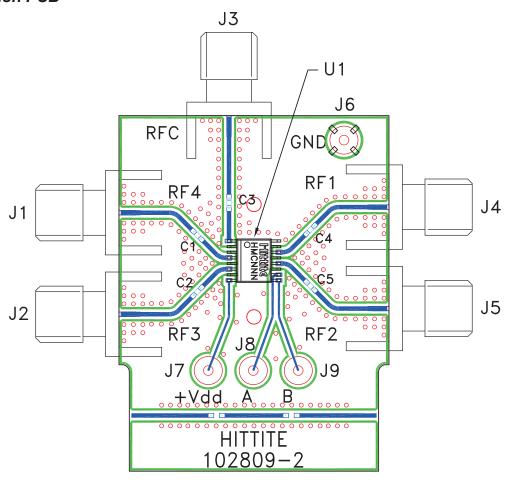


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Evaluation PCB



List of Materials for Evaluation PCB 102913 [1]

Item	Description
J1 - J5	PCB Mount SMA RF Connector
J6 - J9	DC Pin
C1 - C5	330 pF capacitor, 0402 Pkg.
U1	HMC241QS16 / HMC241QS16E SP4T Switch
PCB [2]	102809 Evaluation PCB

^[1] Reference this number when ordering complete evaluation PCB

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 ohm impedance and the package ground leads should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.

^[2] Circuit Board Material: Rogers 4350